

Photo IC diode

S7183, S7184

Linear current amplification of photodiode output



S7183 and S7184 consist of a photodiode and a signal processing circuit for amplifying the photocurrent generated from the photodiode up to 1300 times. Despite a small active area, these photo ICs provide an output nearly equal to that from photodiodes with a 20 × 20 mm active area. Both S7183 and S7184 can be used the same way as a reverse-biased photodiode, and in most cases, they deliver a sufficient output voltage by just connecting a load resistor.

Features

- Clear plastic package
- Operation just as easy as using photodiodes
- Large output current rivaling that of a phototransistor
- Good linearity

Applications

- Energy saving sensors for TV brightness controls, etc.
- Light dimmers for liquid crystal panels
- Various types of light level measurement

■ Absolute maximum ratings (Ta=25 °C)

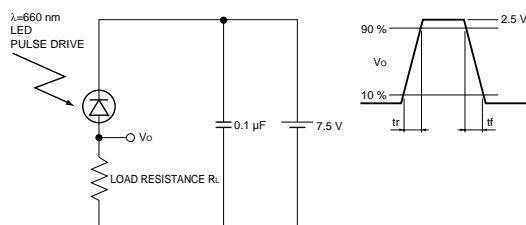
Parameter	Symbol	Value	Unit
Reverse voltage	V _R	-0.5 to 16	V
Photocurrent	I _L	10	mA
Forward current	I _F	10	mA
Power dissipation *1	P	250	mW
Operating temperature	T _{opr}	-30 to +80	°C
Storage temperature	T _{stg}	-40 to +85	°C
Soldering	-	S7183	260 °C, 3 s, at least 2.5 mm away from package surface
		S7184	230 °C, 5 s,

*1: Derate power dissipation at a rate of 3.3 mW/°C above Ta=25 °C

■ Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectral response range	λ		-	300 to 1000	-	nm
Peak sensitivity wavelength	λ_p		-	650	-	nm
Operating reverse voltage	V _R		3	-	12	V
Dark current	I _D	V _R =5 V	-	0.5	10	nA
Photocurrent	I _L	V _R =5 V	0.75	1.0	1.25	mA
		2856 K	S7183, 100 lx	1.4	1.8	
Rise/fall time	t _r , t _f	10 to 90 %, *2 V _R =5 V, R _L =10 k Ω λ =660 nm	-	0.6	-	ms

*2: Rise/fall time measurement method



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